

Data Sheet

Description

The MGD623S is 600 V trench IGBT. Sanken original trench structure decreases gate capacitance, and achieves high speed switching and switching loss reduction. Thus, the IGBT can improve the efficiency of your circuit.

Features

- Low Saturation Voltage
- High Speed Switching
- With Integrated Low V_F Fast Recovery Diode
- Bare Lead Frame: Pb-free (RoHS Compliant)

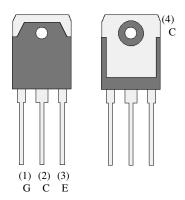
• V _{CE}	600 V
0.2	37 A
- , - ,	1.8 V typ.
	120 ns typ.
	1 2 V tvp

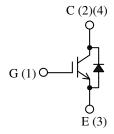
Applications

- Microwave Oven
- IH Cooker
- Inverter Circuit

Package

TO3P-3L





Not to scale

MGD623S

Absolute Maximum Ratings

Unless otherwise specified, $T_A = 25$ °C.

Parameter	Symbol	Conditions	Rating	Unit	Remarks
Collector to Emitter Voltage	V _{CE}		600	V	
Gate to Emitter Voltage	V_{GE}		±30	V	
Continuous Collector Current	т	$T_C = 25 ^{\circ}C$	50	A	
	$I_{\rm C}$	$T_C = 100 ^{\circ}C$	37	A	
Pulsed Collector Current	$I_{C(PULSE)}$	$P_W \le 1 \text{ ms},$ duty cycle $\le 1\%$	100	A	
Diode Continuous Forward Current	I_{F}	$T_C = 25 ^{\circ}C$	30	A	
Diode Pulsed Forward Current	$I_{F(PULSE)}$	$P_W \le 1 \text{ ms},$ duty cycle $\le 1\%$	60	A	
Maximum Collector to Emitter dv/dt	dv/dt	$T_C \le 125 ^{\circ}\text{C}$, see Figure 1	5	V/ns	
Power Dissipation	P_{D}	T _C = 25 °C	150	W	
Operating Junction Temperature	T_{J}		150	°C	
Storage Temperature	T_{STG}		-55 to 150	°C	

Thermal Characteristics

Unless otherwise specified, $T_A = 25$ °C.

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	Remarks
Thermal Resistance of IGBT (Junction to Case)	$R_{\theta JC(IGBT)}$			_	0.833	°C/W	
Thermal Resistance of Diode (Junction to Case)	$R_{\theta JC(Di)}$		_		1.67	°C/W	

MGD623S

Electrical Characteristics

Unless otherwise specified, $T_A = 25$ °C.

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector to Emitter Breakdown Voltage	V _{(BR)CES}	$I_C = 100 \mu A, V_{GE} = 0 V$	600	_	_	V
Collector to Emitter Leakage Current	I_{CES}	$V_{CE} = 600 \text{ V}, V_{GE} = 0 \text{ V}$	_		100	μA
Gate to Emitter Leakage Current	I_{GES}	$V_{GE} = \pm 30 \text{ V}$	_		±500	nA
Gate Threshold Voltage	$V_{\text{GE(TH)}}$	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	3	4.5	6	V
Collector to Emitter Saturation Voltage	V _{CE(sat)}	$V_{GE} = 15 \text{ V}, I_{C} = 50 \text{ A}$	_	1.8	2.4	V
Input Capacitance	C_{ies}	$V_{CE} = 20 \text{ V},$	_	2500	_	pF
Output Capacitance	Coes	$V_{GE} = 0 V$,	_	150	_	
Reverse Transfer Capacitance	C _{res}	f = 1.0 MHz		80	_	
Total Gate Charge	Q_{G}	$V_{CE} = 300 \text{ V}$ $I_{C} = 50 \text{ A}$		65	_	nC
Gate to Emitter Charge	Q_{GE}			20		
Gate to Collector Charge	Q_{GC}	$V_{GE} = 15 \text{ V}$	_	20	_	
Turn-on Delay Time	t _{d(on)}		_	75	_	ns
Rise Time	$t_{\rm r}$	$T_{\rm J}$ = 25 °C,		100		
Turn-off Delay Time	$t_{d(off)}$	see Figure 1	_	300	_	
Fall Time	t_{f}	_		120		
Turn-on Delay Time	t _{d(on)}	$T_J = 125$ °C, see Figure 1		75		
Rise Time	$t_{\rm r}$			100		
Turn-off Delay Time	$t_{d(off)}$			300		ns
Fall Time	t_{f}	1		200		
Emitter to Collector Diode Forward Voltage	$V_{\rm F}$	$I_F = 30 \text{ A}$	_	1.2	1.6	V
Emitter to Collector Diode Reverse Recovery Time	t _{rr}	$I_F = 30 \text{ A},$ $di/dt = 100 \text{ A/}\mu\text{s}$	_	300	_	ns

Test Circuits and Waveforms

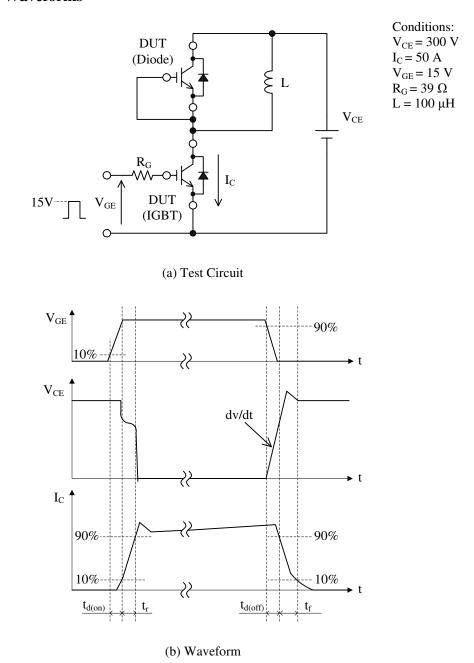


Figure 1. Test Circuits and Waveforms of dv/dt and Switching Time

Rating and Characteristic Curves

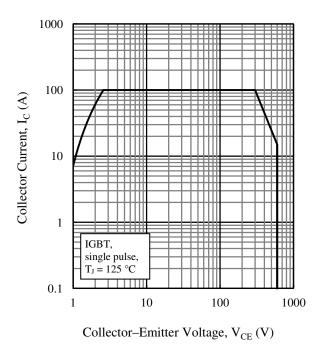


Figure 2. IGBT Reverse Bias Safe Operating Area

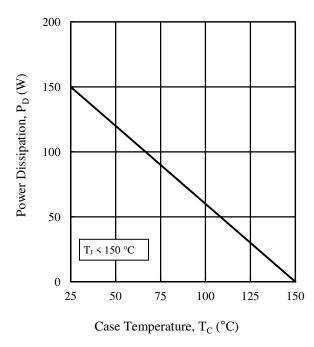


Figure 4. Power Dissipation vs. Case Temperature

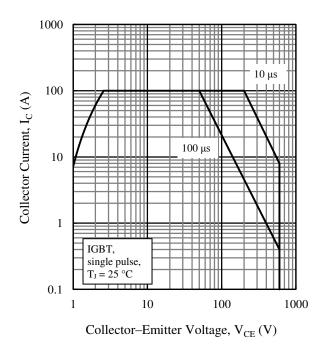


Figure 3. IGBT Safe Operating Area

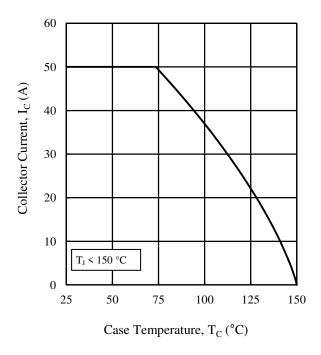


Figure 5. Collector Current vs. Case Temperature

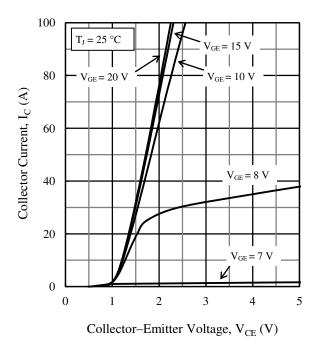


Figure 6. Output Characteristics ($T_J = 25$ °C)

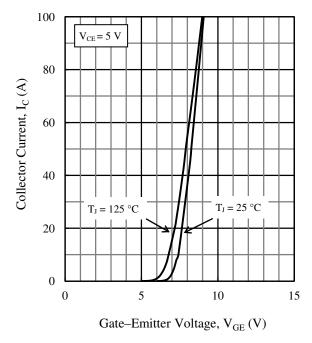


Figure 8. Transfer Characteristics

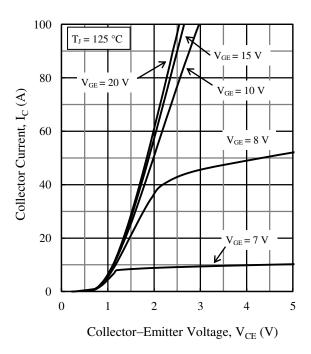


Figure 7. Output Characteristics ($T_J = 125$ °C)

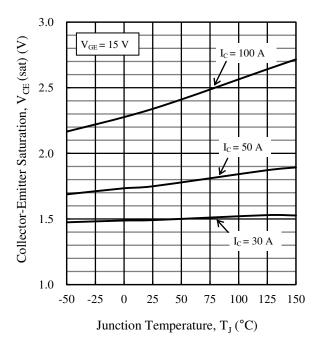


Figure 9. Saturation Voltage vs. Junction Temperature

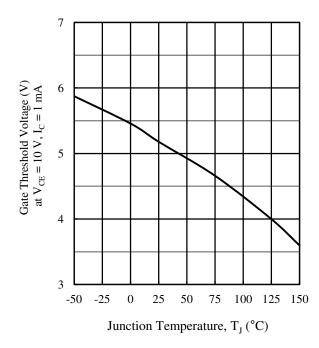


Figure 10. Gate Threshold Voltage vs. Junction Temperature

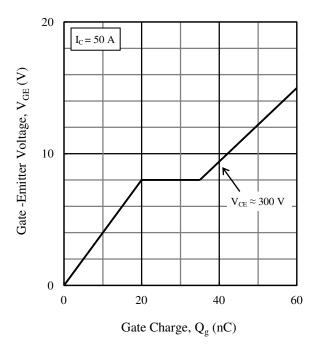


Figure 12. Typical Gate Charge

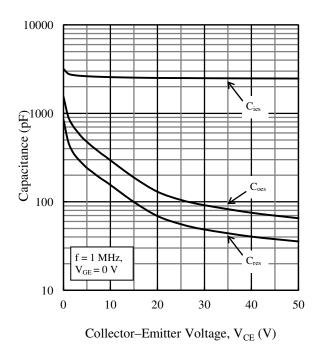


Figure 11. Capacitance Characteristics

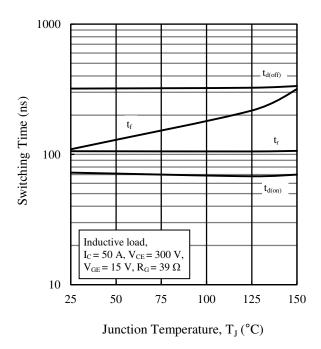


Figure 13. Switching Time vs. Junction Temperature

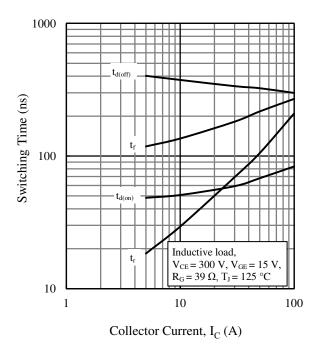


Figure 14. Switching Time vs. Collector Current

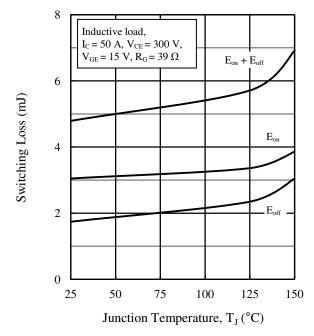


Figure 16. Switching Loss vs. Junction Temperature

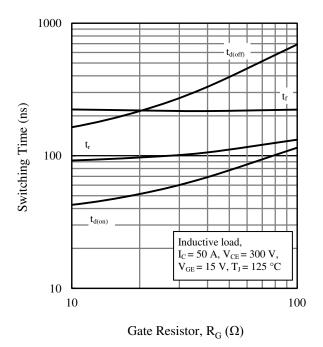


Figure 15. Switching Time vs. Gate Resistor

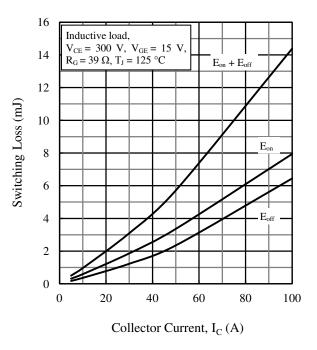


Figure 17. Switching Loss vs. Collector Current

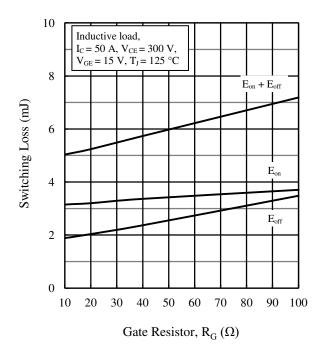


Figure 18. Switching Loss vs. Gate Resistor

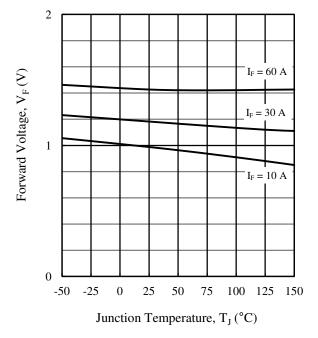


Figure 20. Diode Forward Voltage vs. Junction Temperature

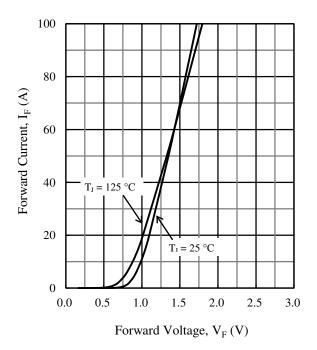


Figure 19. Diode Forward Characteristics

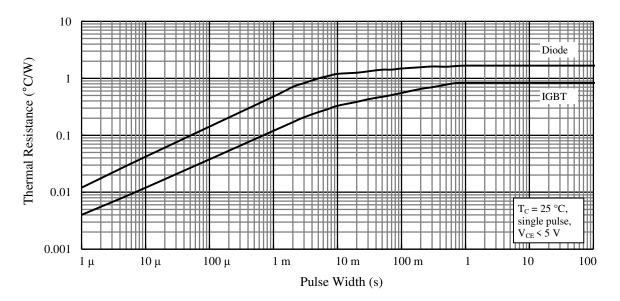
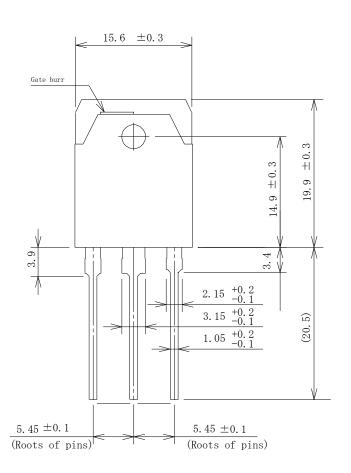
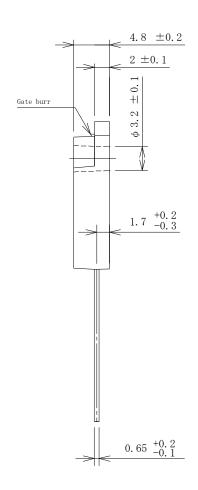


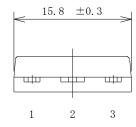
Figure 21. Transient Thermal Resistance

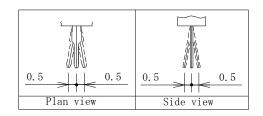
Physical Dimension

• TO3P-3L









NOTES:

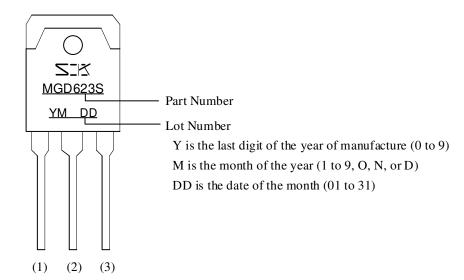
- Dimensions in millimeters
- Maximum gate burr height is 0.3 mm
- Bare lead frame: Pb-free (RoHS compliant)
- When soldering the products, be sure to minimize the working time within the following limits:

Flow: 260 ± 5 °C / 10 ± 1 s, 2 times

Soldering iron: 380 ± 10 °C / 3.5 ± 0.5 s, 1 time (Soldering should be at a distance of at least 1.5 mm from the body of the product.)

- Recommended screw torque: 0.686 N·m to 0.882 N·m (7 kgf·cm to 9 kgf·cm)

Marking Diagram



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